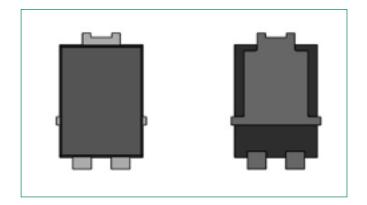
Schottky Barrier Rectifier DST1045S-A, 10A, 45V, TO-277B, Single

DST1045S-A







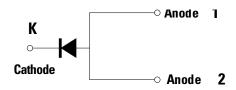


Description

Littelfuse DST series Ultra Low VF Schottky Barrier Rectifier is designed to meet the general requirements of commercial and industry applications by providing high temperature, low leakage, and lower VF products.

It is suitable for high frequency switching mode power supply applications, such as free-wheeling and polarity protection diodes.

Pin out



Features

- Ultra low forward voltage
- High frequency operation
- High junction temperature capability
- Trench MOS Barrier Schottky technology
- Single die in TO-277B Package
- High Reliability application and AEC-Q101 qualified

Applications

- Switching mode power supply
- DC/DC converters
- Free-Wheeling diodes
- Polarity Protection Diodes

Maximum Ratings

Parameters	Symbol	Test Conditions	Max	Unit
Peak Inverse Voltage	V _{RWM}	-	45	V
Average Forward Current *	I _{F(AV)}	50% duty cycle @T _L = 125 °C rectangular wave form	10	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	150	А

^{*} Mounted on 30 mm x 30 mm pad areas aluminum PCB

Electrical Characteristics

Parameters	Symbol	Test Conditions	Тур	Max	Unit
Forward Voltage Drop *	V _{F1}	@5A, Pulse, T _J = 25 °C	0.43	0.51	V
		@10A, Pulse, T _J = 25 °C	0.49	0.57	
	V _{F2}	@5A, Pulse, T _J = 125 °C	0.32	0.43	
		@10A, Pulse, T _J = 125 °C	0.41	0.50	
Reverse Current *	I _{R1}	$@V_R = ratedV_{R,T_J} = 25 ^{\circ}C$	0.017	0.80	mA
	I _{R2}	$@V_R = \text{rated } V_{R_i} T_J = 125 ^{\circ}\text{C}$	15	100	IIIA
Junction Capacitance	C_{T}	$@V_R = 5V, T_C = 25 ^{\circ}C, f_{SIG} = 1MHz$	656	-	pF

^{*} Pulse Width < 300µs, Duty Cycle <2%



Thermal-Mechanical Specifications					
Parameters	Symbol	Test Conditions	Max	Unit	
Junction Temperature	T _J	-	-55 to +150	°C	
Storage Temperature	T _{stg}	-	-55 to +150	°C	
Thermal Resistance Junction to Ambient	R _{eJA}	DC operation	75	°C/W	
Typical Thermal Resistance Junction to Lead	R _{eJL} *	DC operation	3.5	°C/W	
Approximate Weight	wt	-	0.08	g	
Case Style	TO-277B				

- 1. Free air, mounted on recommended copper pad area; thermal resistance $R_{\Theta_{MA}}$ junction to ambient
- 2. Mounted on 30 mm x 30 mm pad areas aluminum PCB; thermal resistance $R_{\Theta,\parallel}$ junction to lead
- * Lead temperature monitored at the cathode pin

Figure 1: Forward Current Derating Curve

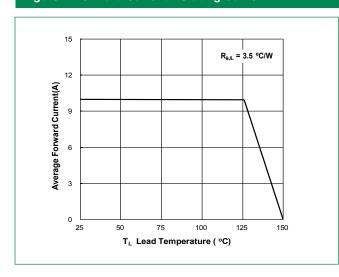


Figure 2: Forward Power Loss Characteristics

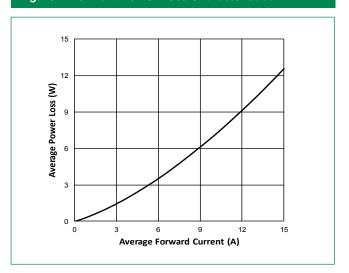


Figure 3: Typical Instantaneous Forward Voltage Characteristics

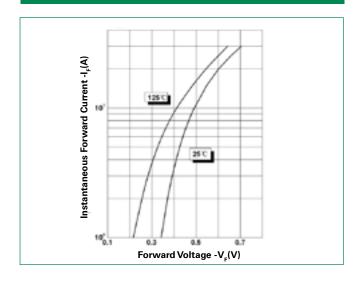


Figure 4: Typical Reverse Characteristics

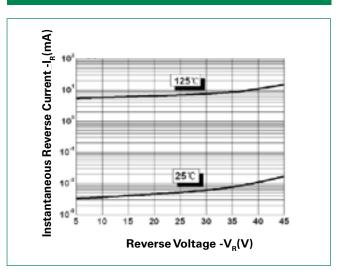
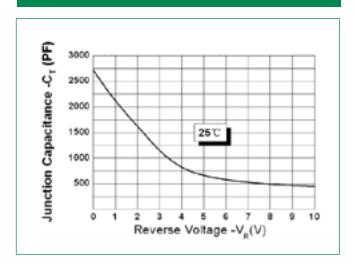
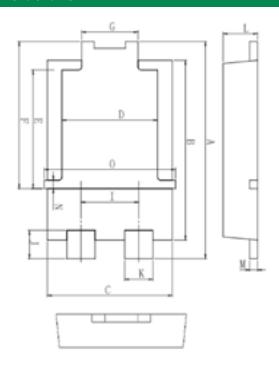




Figure 5: Typical Junction Capacitance



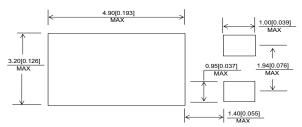
Dimensions-TO-277B



Symbol	Millimeters				
Зушьог	Min	Тур	Max		
А	6.30	6.50	6.70		
В	5.28	5.38	5.48		
С	3.88	3.98	4.08		
D	2.90	3.05	3.20		
Е	3.40	3.55	3.70		
F	4.20	4.40	4.60		
G	1.70	1.80	1.90		
I	1.74	1.84	1.94		
J	0.65	0.85	1.05		
K	0.85	0.90	0.95		
L	0.95	1.10	1.25		
М	0.20	0.25	0.30		
N	0.25	0.40	0.55		
0	4.00	4.05	4.25		

Part Numbering and Marking System

Mounting Pad Layout



DST1045 S-A LF YYWWL

DST = CompnentType

10 = Forward Current (10A)

45 = Reverse Voltage (45V)

S = PackageType

A = AEC-Q101 Qualified Component

LF = Littelfuse

YY =Year

WW = Week

L = Lot Number

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